SM5817 THRU SM5819

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS

Reverse Voltage - 20 to 40 V Forward Current - 1 A

Features

- Fast switching
- Glass passivated device
- Ideal for surface mounted applications
- Low leakage current
- Metallurgically bonded construction

Mechanical data

- Case: MELF (DO-213AB) molded plastic
- Mounting position: Any

5.2 4.8 $\frac{1}{0.60}$ $\frac{2.7}{2.4}$ SOLDERABLE ENDS

Plastic case MELF (DO-213AB) Dimensions in millimeters

Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave,60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter		Symbols	SM5817	SM5818	SM5819	Units
Maximum Repetitive Peak Reverse Voltage		V _{RRM}	20	30	40	V
Maximum RMS Voltage		V _{RMS}	14	21	28	V
Maximum DC Blocking Voltage		V _{DC}	20	30	40	V
Maximum Average Forward Rectified Current at $T_A = 90 ^{\circ}C$		I _{F(AV)}	1			A
Peak Forward Surge Current 8.3 ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC method)		I _{FSM}	25			А
Maximum Instantaneous Forward Voltage at 1 A DC		V _F	0.45	0.55	0.6	V
Maximum Instantaneous Forward Voltage at 3.1 A DC		V _F	0.75	0.875	0.9	V
Maximum Average Reverse Current at Rated DC Blockingat $T_A = 2$ Voltageat $T_A = 1$	5 °C 00 °C	I _R 1 10			mA	
Typical Thermal Resistance ¹⁾		$R_{\theta JA}$	80			°C/W
Typical Junction Capacitance ²⁾		CJ		110		pF
Operating and Storage Temperature Range		T_{j},T_{stg}		- 65 to + 125	5	°C

¹⁾ Thermal Resistance (Junction to Ambient): Vertical PC Board Mounting, 0.5" (12.7 mm) Lead Length.

²⁾ Measured at 1 MHz and applied reverse voltage of 4 volts.





